Clock OSC

SG5032CCN

SG5032CCN 3.686400 MHz HJGA Product name Product Number / Ordering code

X1G0044710026xx

Please refer to the 8.Packing information about xx (last 2 digits)

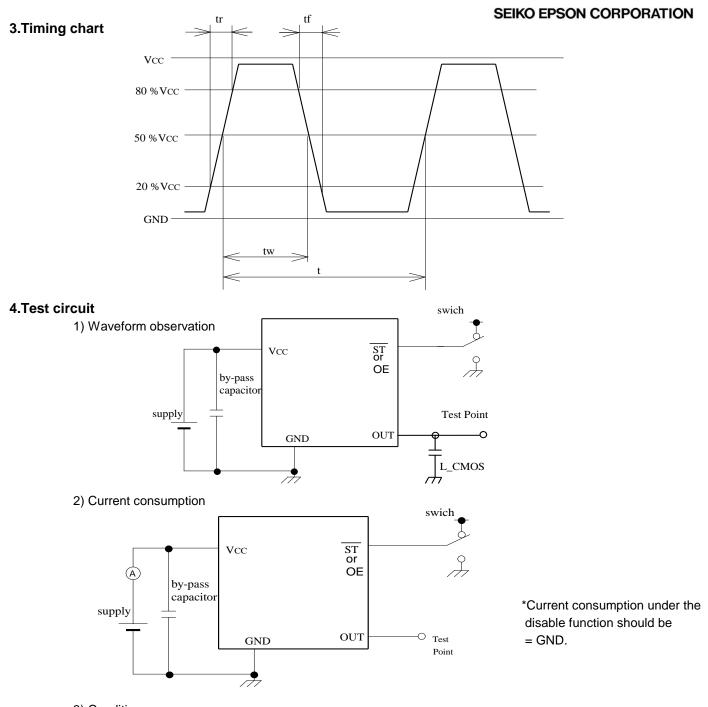
Output waveform CMOS

Pb free / Complies with EU RoHS directive

Reference weight Typ. 52 mg

| 1.Absolute maximum ratings | | | | | | |
|----------------------------|---------|------|------|---------|------|---------------------------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions / Remarks |
| Maximum supply voltage | Vcc-GND | -0.3 | - | 7 | V | - |
| Storage temperature | T_stg | -40 | - | 125 | °C | Storage as single product |
| Input voltage | Vin | -0.5 | - | Vcc+0.5 | V | OE terminal |

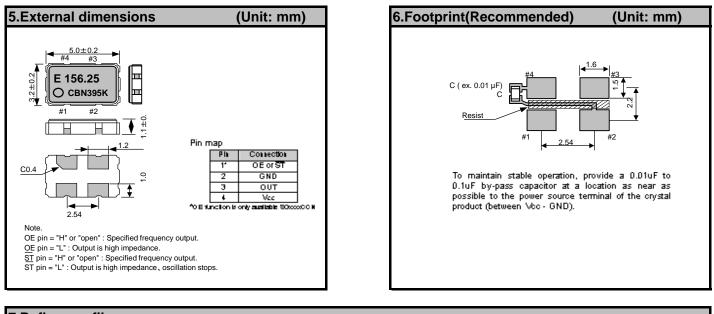
| 2.Specifications(characteris | tics) | | | | | |
|------------------------------|------------------|---------|--------|--------|-------------------|---|
| Parameter | Symbol | Min. | Тур. | Max. | Unit | Conditions / Remarks |
| Output frequency | fO | | 3.6864 | | MHz | |
| Supply voltage | Vcc | 4.5 | 5 | 5.5 | V | - |
| Operating temperature | T_use | -40 | - | 85 | °C | - |
| Frequency tolerance | f_tol | -50 | - | 50 | x10 ⁻⁶ | T_use |
| Current consumption | lcc | - | - | 20 | mA | No load condition |
| Stand-by current | I_std | - | - | - | μA | - |
| Disable current | I_dis | - | - | 10.0 | mA | OE = GND |
| Symmetry | SYM | 40 | - | 60 | % | 50% Vcc Level L_CMOS=<50pF |
| Output voltage | V _{OH} | Vcc-0.4 | - | - | | - |
| | V _{OL} | - | - | 0.4 | | - |
| Output load condition | L_CMOS | - | - | 50 | pF | CMOS Load |
| Input voltage | V _{IH} | 0.8Vcc | - | - | | OE terminal |
| | V _{IL} | - | - | 0.2Vcc | | OE terminal |
| Rise time | t _r | - | - | 5 | ns | 0.2Vcc to 0.8Vcc Level, L_CMOS=50pF |
| Fall time | tf | - | - | 5 | ns | 0.2Vcc to 0.8Vcc Level, L_CMOS=50pF |
| Start-up time | t_str | - | - | 5 | ms | t = 0 at 0.9Vcc |
| Jitter | t _{DJ} | - | TBD | - | ps | Deterministic Jitter |
| | T _{RJ} | - | TBD | - | ps | Random Jitter |
| | t _{RMS} | - | TBD | - | ps | δ(RMS of total distribution) |
| | t _{p-p} | - | TBD | - | ps | Peak to Peak |
| | t _{acc} | - | TBD | - | ps | Accumulated Jitter(δ) n=2 to 50000 cycles |
| Phase jitter | t _{PJ} | - | TBD | - | ps | Off set Frequency: 12kHz to 20MHz |
| Phase noise | L(f) | - | TBD | - | dBc/Hz | Off set 1Hz |
| | | - | TBD | - | dBc/Hz | Off set 10Hz |
| | | - | TBD | - | dBc/Hz | Off set 100Hz |
| | | - | TBD | - | dBc/Hz | Off set 1kHz |
| | | - | TBD | - | dBc/Hz | Off set 10kHz |
| | | - | TBD | - | dBc/Hz | Off set 100kHz |
| | | - | TBD | - | dBc/Hz | Off set 1MHz |
| Frequency aging | f_age | -5 | - | 5 | x10 ⁻⁶ | @+25°C first year |
| | | - | - | - | | - |

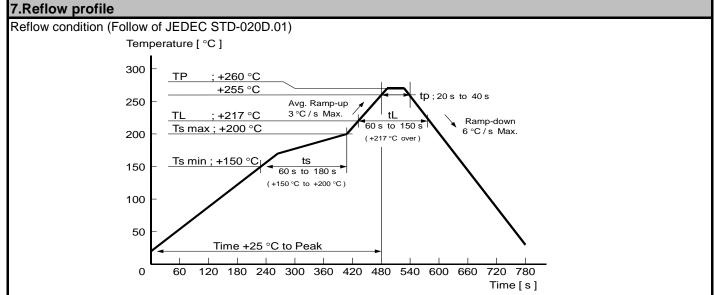


3) Condition

- (1) Oscilloscope
- · Band width should be minimum 5 times higher (wider) than measurement frequency.
- · Probe earth should be placed closely from test point and lead length should be as short as possible
- * Recommendable to use miniature socket. (Don't use earth lead.)
- (2) L_CMOS also includes probe capacitance.
- (3) By-pass capacitor (0.01 mF to 0.1 mF) is placed closely between VCC and GND.
- (4) Use the current meter whose internal impedance value is small.
- (5) Power supply
- \cdot Start up time (0 %VCC \circledast 90 %VCC) of power source should be more than 150 ms.
- \cdot Impedance of power supply should be as lowest as possible.

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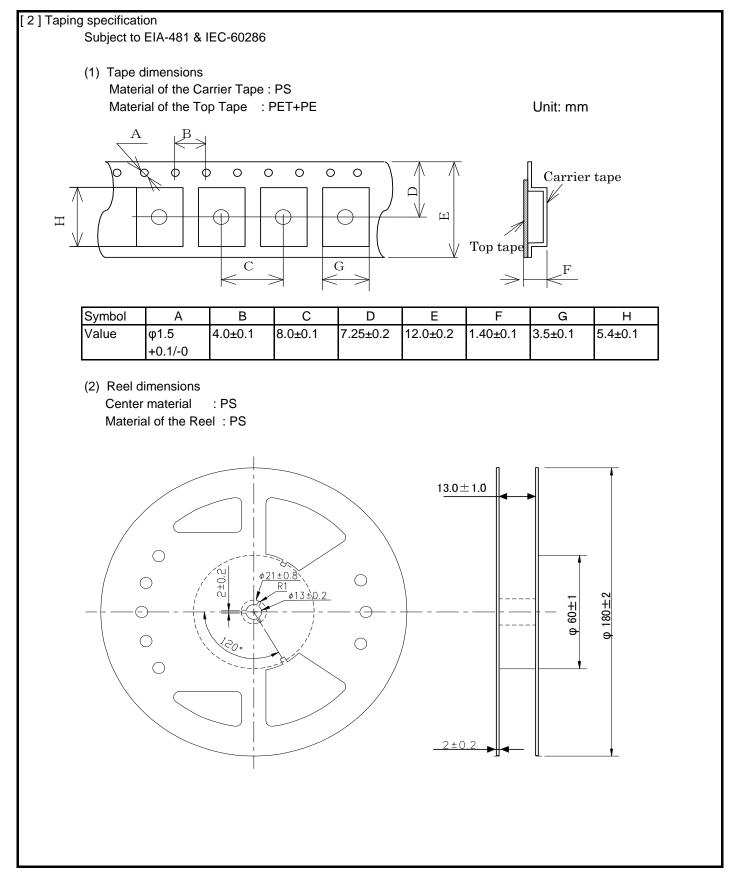




8.Packing information

| [1]Produc | t number la | ast 2 digits code(xx) description | | The recommended code is "00" |
|-----------|-------------|-----------------------------------|------|------------------------------|
| | X1G0044 | 710026xx | | |
| | Code | Condition | Code | Condition |
| | 01 | Any Q'ty vinyl bag(Tape cut) | 13 | 500pcs / Reel |
| | 11 | Any Q'ty / Reel | 00 | 1000pcs / Reel |
| | 12 | 250pcs / Reel | | |

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